


MDT0096AIH-SPI	80 x 160	SPI Interface	TFT Module
Specification			
Version: 1		Date: 26/06/2018	
Revision			
1	25/06/2018	First issue	

Display Features			
Display Size	0.96"		
Resolution	80 x 160		
Orientation	Portrait		
Appearance	RGB		
Logic Voltage	3.3V		
Interface	SPI		
Brightness	500 cd/m ²		
Touchscreen	---		
Module Size	13.50 x 27.95 x 1.40mm		
Operating Temperature	-20°C ~ +70°C		
Pinout	13 way FFC		Box Quantity
Pitch	0.8mm		Weight / Display
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* - For full design functionality, please use this specification in conjunction with the ST7735S specification.(Provided Separately)

Display Accessories	
Part Number	Description

Optional Variants	
Appearances	Voltage



Summary

MDT0096AIH-SPI is a color active matrix thin film transistor (TFT) liquid crystal empty cell. This model is composed of amorphous silicon TFT as a switching device. It is a transmissive type display operating in the normally black mode.

This TFT LCD has a 0.96-inch diagonally measured active display area with 80 x 160 dot (80 horizontal by 160 vertical pixel) resolution. Each pixel is divided into Red, Green, Blue dots which are arranged in vertical stripes.

General Specifications

- Size: 0.96 inch
- Dot Matrix: 80 x RGB x 160(TFT) dots
- Module dimension: 13.5(W) x 27.95(H) x 1.40(D) mm
- Active area: 10.8 x 21.696 mm
- Dot pitch: 0.135 x 0.1356 mm
- LCD type: TFT, Normally black, Transmissive
- Viewing Angle: 80/80/80/80
- Aspect Ratio: 1:2
- IC: ST7735S
- Backlight Type: LED, Normally White
- With /Without TP: Without TP
- Surface: Glare

*Color tone slight changed by temperature and driving voltage.



Interface

1. LCM PIN Definition

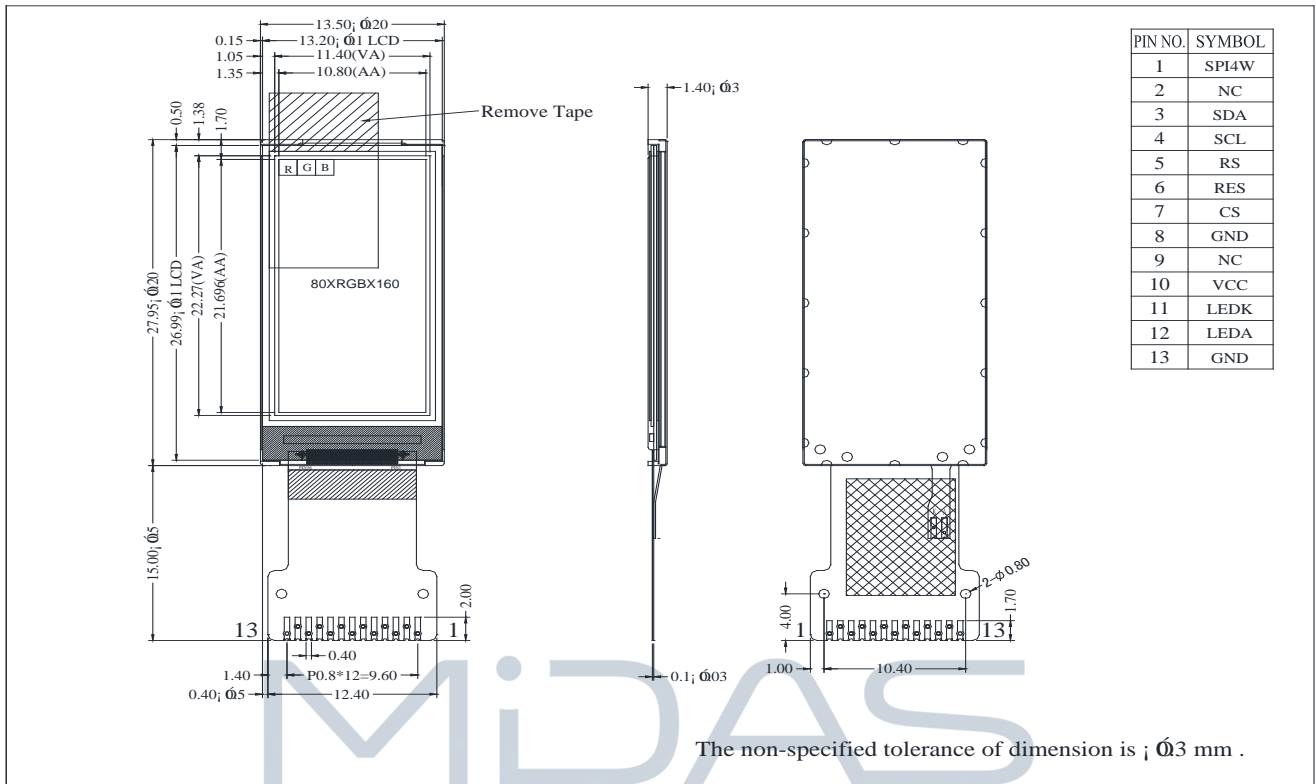
Pin	Symbol	Function	Remark
1	SPI4W	SPI4W='0', 3-wire SPI. SPI4W='1', 4-wire SPI.	
2	NC	No connection	
3	SDA	Serial interface data	
4	SCL	Serial interface clock	
5	RS	Data/command selection pin (4-wire SPI use)	
6	RES	Reset pin (low active)	
7	CS	Chip selection pin (low active)	
8	GND	Ground	
9	NC	No connection	
10	VCC	Power supply.	
11	LEDK	Back light cathode	
12	LEDA	Back light anode	
13	GND	Ground	

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Absolute Maximum Ratings

Item	Symbol	Min	Typ	Max	Unit
Operating Temperature	TOP	-20	—	+70	°C
Storage Temperature	TST	-30	—	+80	°C

Note: Device is subject to be damaged permanently if stresses beyond those absolute maximum ratings listed above

1. Temp. $\leq 60^{\circ}\text{C}$, 90% RH MAX. Temp. $> 60^{\circ}\text{C}$, Absolute humidity shall be less than 90% RH at 60°C

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Electrical Characteristics

1. Operating conditions:

Item	Symbol	Min	Typ	Max	Unit
Supply Voltage	VCC	3.0	3.3	3.6	V
Supply LCM current	ICC	—	—	2	mA

2.LED driving conditions

Parameter	Symbol	Min.	Typ.	Max.	Unit	Remark
LED current	I _{LED}	—	20	—	mA	
LED voltage	V _{LED}	2.8	3.1	3.3	V	Note 1
LED Life Time		—	50000	—	Hr	Note 2,3,4

Note 1 : There are 1 Groups LED



Note 2 : Ta = 25 °C

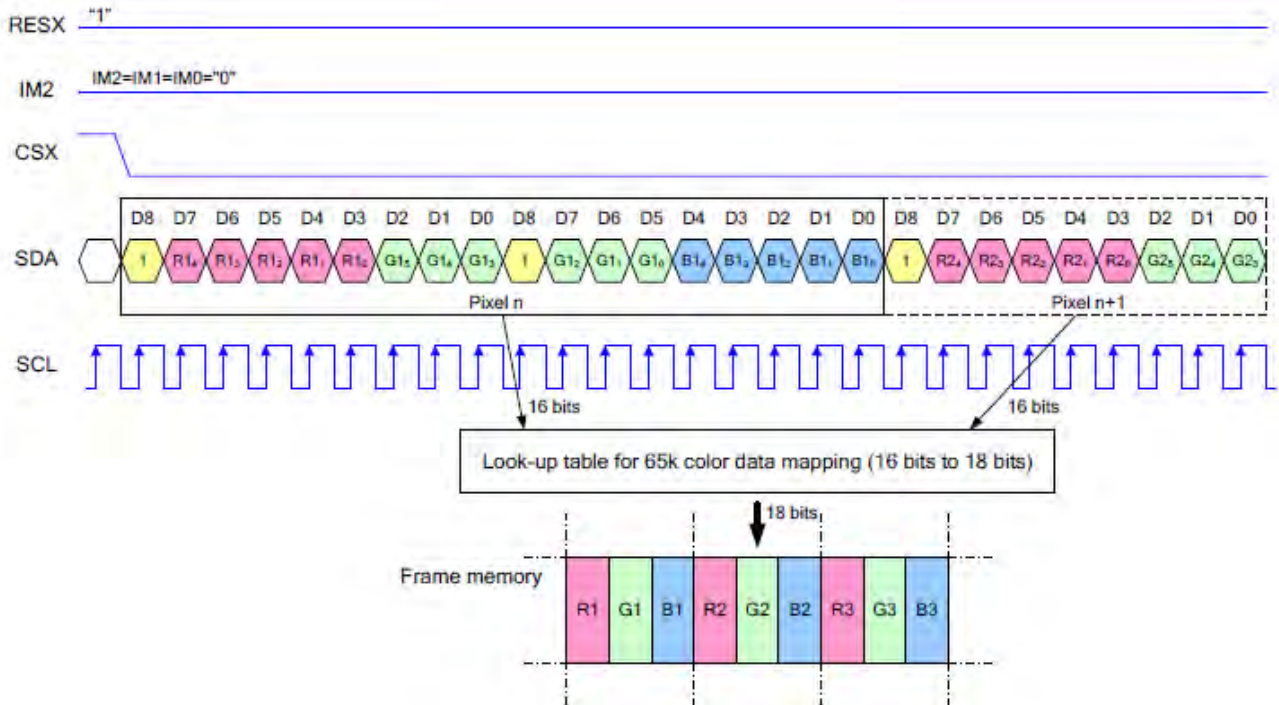
Note 3 : Brightness to be decreased to 50% of the initial value

Note 4 : The single LED lamp case



Data Color Coding

1. 3-Wire SPI Mode: RGB 5-6-5-bit Input, 65K-Colors, 3AH="05h"



Note 1: Pixel data with the 16-bit color depth information

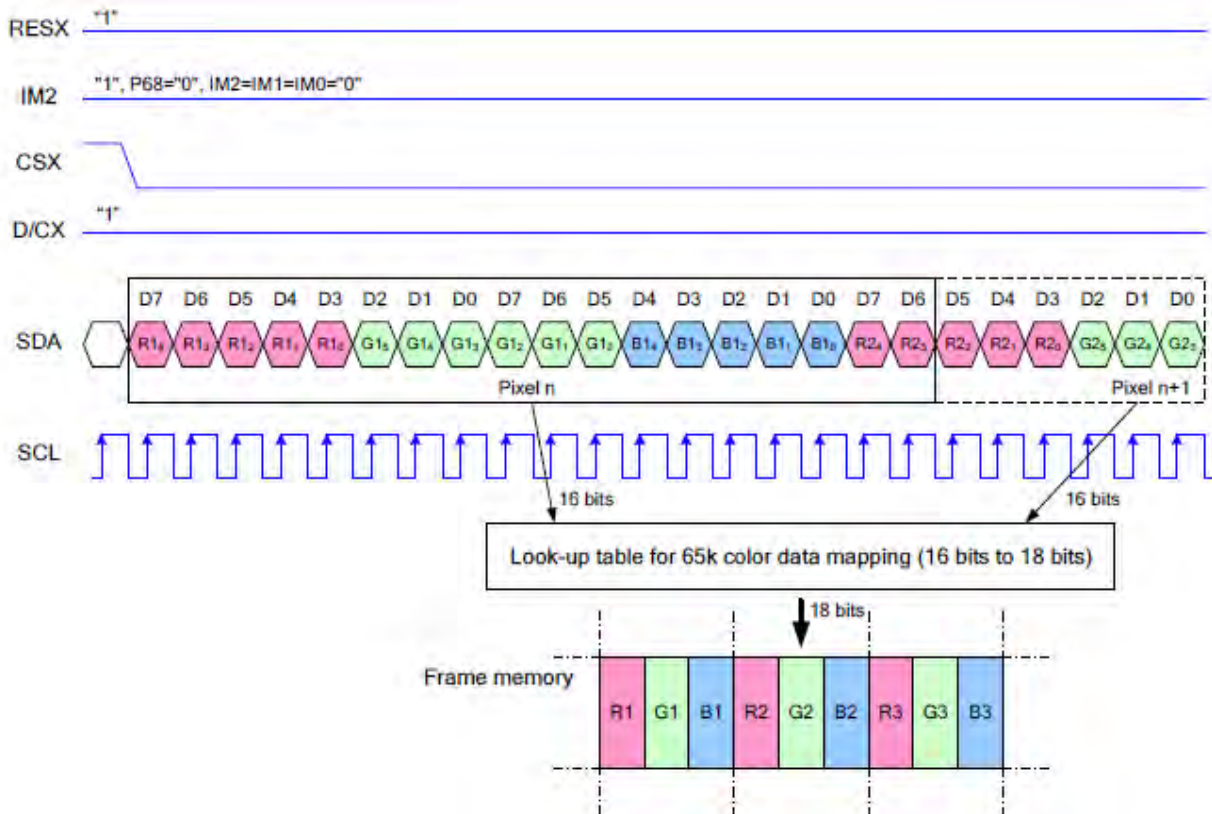
Note 2: The most significant bits are: Rx4, Gx5 and Bx4

Note 3: The least significant bits are: Rx0, Gx0 and Bx0

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2. 4-Wire SPI Mode: RGB 5-6-5-bit Input, 65K-Colors, 3AH="05h"



Note 1. Pixel data with the 16-bit color depth information

Note 2. The most significant bits are: Rx4, Gx5 and Bx4

Note 3. The least significant bits are: Rx0, Gx0 and Bx0

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Optical Characteristics

Item	Symbol	Condition.	Min	Typ.	Max.	Unit	Remark
Response time	Tr	$\theta=0^\circ$ 、 $\Phi=0^\circ$	-	30	40	.ms	Note 3,5
	Tf						
Contrast ratio	CR	At optimized viewing angle	-	800	-	-	Note 4,5
Color Chromaticity	White	$\theta=0^\circ$ 、 $\Phi=0^\circ$	0.26	0.31	0.36		Note 2,6,7
Viewing angle	Hor.	Θ_R	-	80	-	Deg.	Note 1
		Θ_L	-	80	-		
	Ver.	Φ_T	-	80	-		
		Φ_B	-	80	-		
Brightness	-	-	400	500	-	cd/m ²	Center of display

Ta=25±2°C

Note 1: Definition of viewing angle range

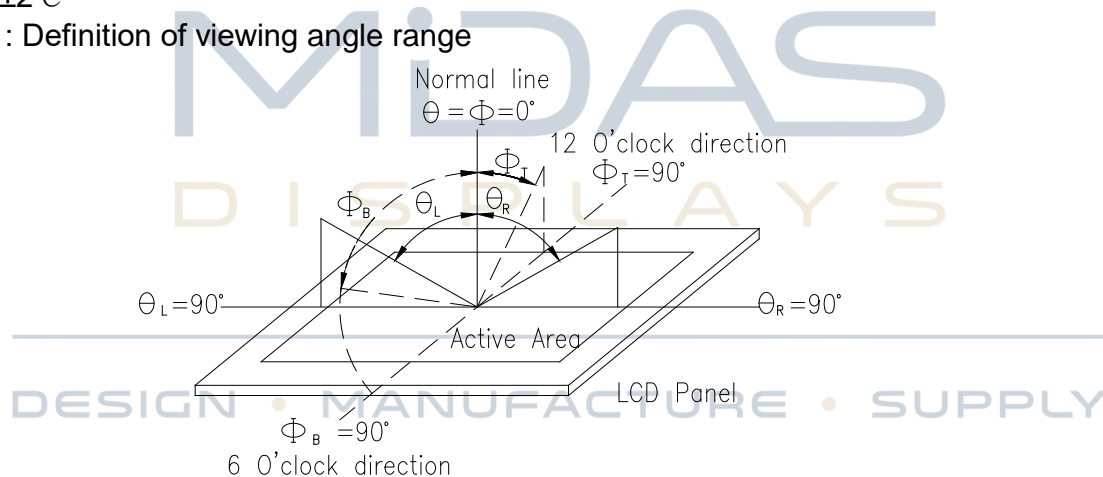


Fig.1. Definition of viewing angle

Note 2: Test equipment setup:

After stabilizing and leaving the panel alone at a driven temperature for 10 minutes, the measurement should be executed. Measurement should be executed in a stable, windless, and dark room. Optical specifications are measured by Topcon BM-7orBM-5 luminance meter 1.0° field of view at a distance of 50cm and normal direction.

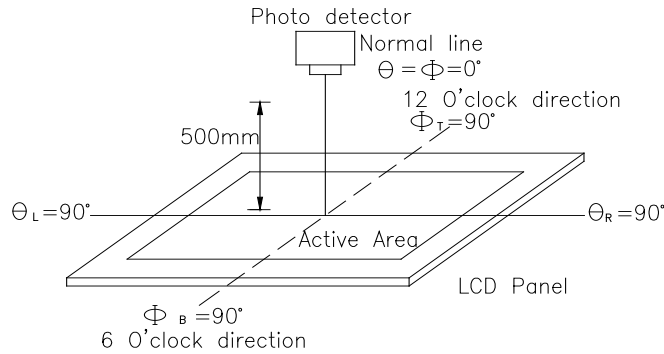
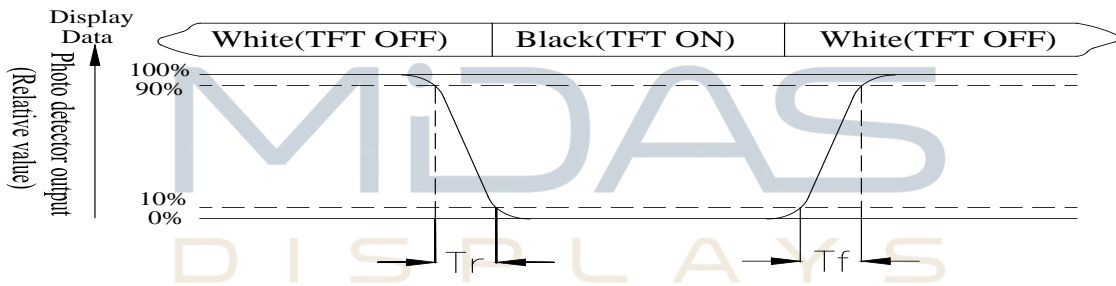


Fig. 2. Optical measurement system setup

Note 3: Definition of Response time:

The response time is defined as the LCD optical switching time interval between “White” state and “Black” state. Rise time, T_r , is the time between photo detector output intensity changed from 90% to 10%. And fall time, T_f , is the time between photo detector output intensity changed from 10% to 90%



Note 4: Definition of contrast ratio:

The contrast ratio is defined as the following expression.

$$\text{Contrast ratio (CR)} = \frac{\text{Luminance measured when LCD on the "White" state}}{\text{Luminance measured when LCD on the "Black" state}}$$

Note 5: White $V_i = V_{i50} \pm 1.5V$

Black $V_i = V_{i50} \pm 2.0V$

“±” means that the analog input signal swings in phase with VCOM signal.

“±” means that the analog input signal swings out of phase with VCOM signal.

The 100% transmission is defined as the transmission of LCD panel when all the input terminals of module are electrically opened.

Note 6: Definition of color chromaticity (CIE 1931)

Color coordinates measured at the center point of LCD

Note 7: Measured at the center area of the panel when all the input terminals of LCD panel are electrically opened.



Reliability

Content of Reliability Test (Wide temperature, -20°C~70°C)

Environmental Test			
Test Item	Content of Test	Test Condition	Note
High Temperature storage	Endurance test applying the high storage temperature for a long time.	80°C 200hrs	2
Low Temperature storage	Endurance test applying the low storage temperature for a long time.	-30°C 200hrs	1,2
High Temperature Operation	Endurance test applying the electric stress (Voltage & Current) and the thermal stress to the element for a long time.	70°C 200hrs	—
Low Temperature Operation	Endurance test applying the electric stress under low temperature for a long time.	-20°C 200hrs	1
High Temperature/ Humidity Operation	The module should be allowed to stand at 60°C,90%RH max	60°C,90%RH 96hrs	1,2
Thermal shock resistance	The sample should be allowed stand the following 10 cycles of operation <div style="text-align: center;"> <p style="text-align: center;">-20°C 25°C 70°C</p> <p style="text-align: center;">30min 5min 30min</p> <p style="text-align: center;">1 cycle</p> </div>	-20°C/70°C 10 cycles	—
Vibration test	Endurance test applying the vibration during transportation and using.	Total fixed amplitude : 1.5mm Vibration Frequency : 10~55Hz One cycle 60 seconds to 3 directions of X,Y,Z for Each 15 minutes	3
Static electricity test	Endurance test applying the electric stress to the terminal.	VS=±600V(contact) ,±800v(air), RS=330Ω CS=150pF 10 times	—

Note1: No dew condensation to be observed.

Note2: The function test shall be conducted after 4 hours storage at the normal Temperature and humidity after remove from the test chamber.

Note3: The packing have to including into the vibration testing.